

LOW DROP DUAL POWER OPERATIONAL AMPLIFIER

- OUTPUT CURRENT TO 1 A
- OPERATES AT LOW VOLTAGES
- SINGLE OR SPLIT SUPPLY
- LARGE COMMON-MODE AND DIFFERENTIAL MODE RANGE
- LOW INPUT OFFSET VOLTAGE
- GROUND COMPATIBLE INPUTS
- LOW SATURATION VOLTAGE
- THERMAL SHUTDOWN
- CLAMP DIODE



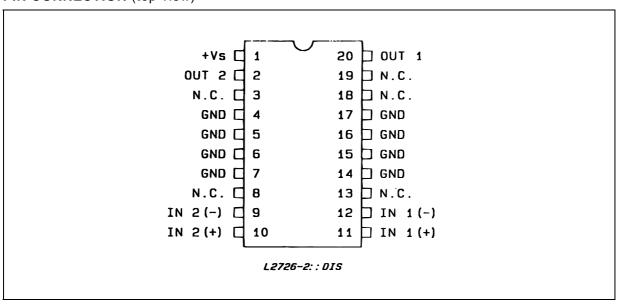
DESCRIPTION

The L2726 is a monolithic integrated circuit in SO-20 package intended for use as power operational amplifiers in a wide range of applications including servo amplifiers and power supplies.

It is particularly indicated for driving inductive loads, as motor and finds applications in compact-disc VCR automative, etc.

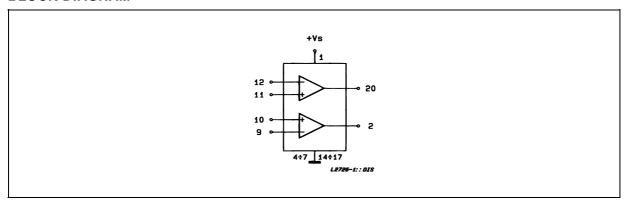
The high gain and high output power capability provide superior performance whatever an operational amplifier/power booster combination is required.

PIN CONNECTION (top view)

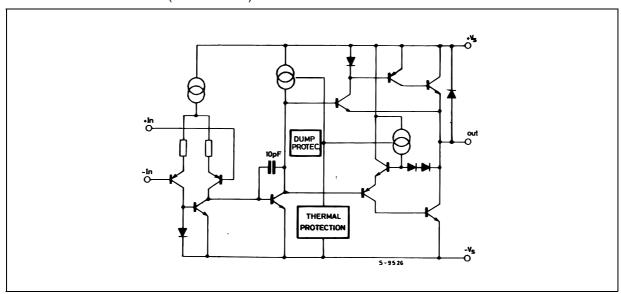


October 1998 1/6

BLOCK DIAGRAM



SCHEMATIC DIAGRAM (one section)



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
Vs	Supply Voltage	28	V
Vs	Peak Supply Voltage (50ms)	50	V
Vi	Input Voltage	V_s	
Vi	Differential Input Voltage	± V _s	
Ιo	DC Output Current	1	Α
Ιp	Peak Output Current (non repetitive)	1.5	Α
P _{tot}	Power Dissipation at $T_{amb} = 85^{\circ}C$ $T_{case} = 75^{\circ}C$	1 5	W
T _{op}	Operating Temperature	- 40 to 85	°C
T_{stg}, T_j	Storage and Junction Temperature	- 40 to 150	°C

THERMAL DATA

R _{th j-case}	Thermal Resistance Junction-case	Max.	15.0	°C/W
R _{th j-amb}	Thermal Resistance Junction-ambient (*)	Max.	65	°C/W

^(*) With 4 sq. cm copper area heatsink.

2/6

ELECTRICAL CHARACTERISTICS

 $V_s = 24V$, $T_{amb} = 25^{\circ}C$ unless otherwise specified

Symbol	Parameter	Test Conditions		Min.	Тур.	Max.	Unit
Vs	Single Supply Voltage			4		28	V
Vs	Split Supply Voltage			± 2		± 14	V
Is	Quiescent Drain Current	$V_0 = \frac{V_s}{2}$	V _s = 24V		10	15	mA
			$V_s = 24V$		9	15	
I _b	Input Bias Current				0.2	1	μΑ
Vos	Input Offset Voltage					10	mV
I _{os}	Input Offset Current					100	nA
SR	Slew Rate				2		V/μs
В	Gain-bandwidth Product				1.2		MHz
Ri	Input Resistance			500			kΩ
G _v	O. L. Voltage Gain	f = 100Hz f = 1kHz		70	80 60		dB
e _N	Input Noise Voltage	B = 22Hz to 22kHz			10		μV
I _N	Input Noise Voltage	D = 22112 to 22k112			200		pА
CMR	Common Mode Rejection	f = 1kHz		66	84		dB
SVR	Supply Voltage Rejection	$ f = 100Hz \\ R_G = 10k\Omega \\ V_R = 0.5V $	$V_s = 24V$ $V_s = \pm 12V$ $V_s = \pm 6V$	60	70 75 80		dB dB dB
V _{DROP(HIGH)}		$V_s = \pm 2.5 V \text{ to } \pm 12 V$	$I_p = 100 \text{mA}$ $I_p = 500 \text{mA}$		0.7 1	1.5	V
V _{DROP(LOW)}		$V_s = \pm 2.5V \text{ to } \pm 12V$	$I_p = 100 \text{mA}$ $I_p = 500 \text{mA}$		0.3 0.5	1	V
Cs	Channel Separation	$f = 1KHz$ $R_L = 10\Omega$ $G_V = 30dB$	V _s = 24V V _s = 6V		60 60		dB
T _{sd}	Thermal Shutdown Junction Temperature			150			°C

Figure 1 : Quiescent Current vs. Supply Voltage

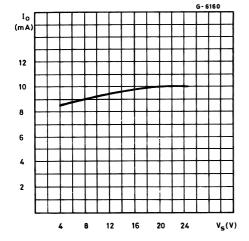


Figure 2: Open Loop Gain vs. Frequency

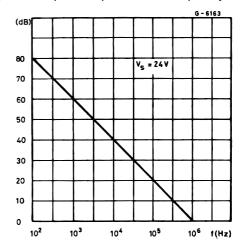


Figure 3 : Common Mode Rejection Frequency

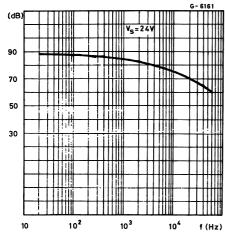


Figure 5 : Output Swing vs. Load Current $(V_s = \pm 12 \text{ V})$

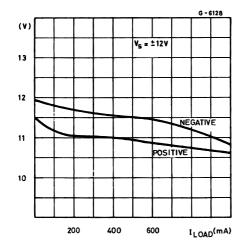


Figure 7: Channel Separation vs. Frequency.

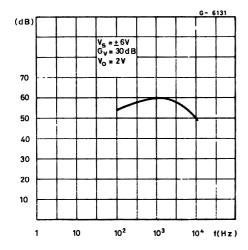


Figure 4 : Output Swing vs. Load Current $(V_s = \pm 5V)$

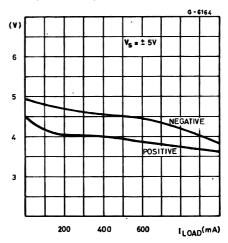
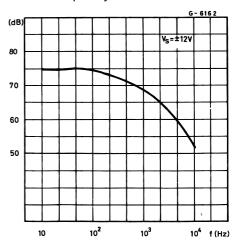


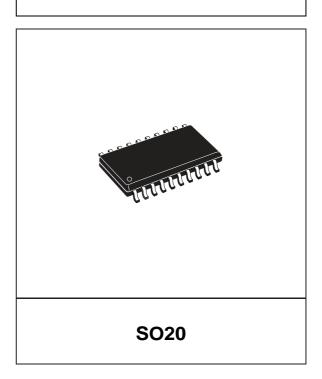
Figure 6 : Supply Voltage Rejection vs. Frequency

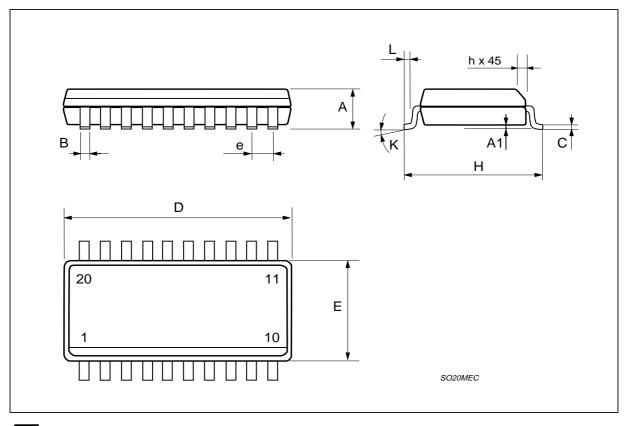


4/6

DIM.	mm			inch			
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	
Α	2.35		2.65	0.093		0.104	
A1	0.1		0.3	0.004		0.012	
В	0.33		0.51	0.013		0.020	
С	0.23		0.32	0.009		0.013	
D	12.6		13	0.496		0.512	
Е	7.4		7.6	0.291		0.299	
е		1.27			0.050		
Н	10		10.65	0.394		0.419	
h	0.25		0.75	0.010		0.030	
L	0.4		1.27	0.016		0.050	
К	0° (min.)8° (max.)						

OUTLINE AND MECHANICAL DATA





Information furnished is believed to be accurate and reliable. However, STMicroelectronics assumes no responsibility for the consequences of use of such information nor for any infringement of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of STMicroelectronics. Specification mentioned in this publication are subject to change without notice. This publication supersedes and replaces all information previously supplied. STMicroelectronics products are not authorized for use as critical components in life support devices or systems without express written approval of STMicroelectronics.

The ST logo is a registered trademark of STMicroelectronics © 1998 STMicroelectronics – Printed in Italy – All Rights Reserved STMicroelectronics GROUP OF COMPANIES

Australia - Brazil - Canada - China - France - Germany - Italy - Japan - Korea - Malaysia - Malta - Mexico - Morocco - The Netherlands - Singapore - Spain - Sweden - Switzerland - Taiwan - Thailand - United Kingdom - U.S.A.

http://www.st.com

